





IN THE UNITED STATES PATENT AND TRADEMARK OFFICE RECEIVED

First Named Inventor :

or : Lujun Chen et al.

Appln. No.: 09/843,370

Filed : April 26, 2001

For : GIANT MAGNETO

: GIANT MAGNETORESISTIVE SENSOR HAVING SELF-CONSISTENT DEMAGNETIZATION FIELDS

Docket No.: S01.12-0730/STL9852

JUL 0 2 2003

Technology Center 2600

Group Art Unit: 2652

Examiner:

Brian

E. elect

Miller

8/17-03

AMENDMENT

Mail Stop Non-Fee Amendment Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450 I HEREBY CERTIFY THAT THIS PAPER IS BEING SENT BY U.S. MAIL, FIRST CLASS, TO THE COMMISSIONER FOR PATENTS, P.O. BOX 1450, ALEXANDRIA, VA 22313-1450, THIS

27 DAY OF JUNE

. 2003.

PATENT ATTORNEY

This Amendment is in response to the Office Action mailed on June 16, 2003. Please amend the above-identified application as follows:

IN THE CLAIMS

Please add new claim 18 and amend claim 17 to read as follows:

Sublin

- 17. (Amended) A method of manufacturing a spin valve sensor for use with a data storage system to produce a giant magnetoresistive (GMR) effect in response to applied magnetic fields, the method comprising steps of:
 - (a) forming a first ferromagnetic (FM) free layer having a magnetization (M_1) in a first direction when in a quiescent state;
 - (b) forming a second FM free layer having a magnetization (M_2) in a second direction that is